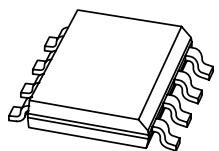


DATA SHEET



KMZ51 **Magnetic field sensor**

Product specification
Supersedes data 1998 Mar 24

2000 Jun 13

Magnetic field sensor

KMZ51

FEATURES

- High sensitivity
- Integrated compensation coil
- Integrated set/reset coil.

APPLICATIONS

- Navigation
- Current and earth magnetic field measurement
- Traffic detection.

DESCRIPTION

The KMZ51 is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. The sensor contains one magnetoresistive Wheatstone bridge and integrated compensation and set/reset coils. The integrated compensation coil allows magnetic field measurement with current feedback loops to generate an output that is independent of drift in sensitivity. The orientation of sensitivity may be set or changed (flipped) by means of the integrated set/reset coil. A short current pulse should be applied to the compensation coil to recover (set) the sensor after exposure to strong disturbing magnetic fields. A negative current pulse will reset the sensor to reversed sensitivity. By use of periodically alternated flipping pulses and a lock-in amplifier, output is made independent of sensor and amplifier offset.

PINNING

| PIN | SYMBOL | DESCRIPTION |
|-----|--------------------|-----------------------|
| 1 | +I _{flip} | flip coil |
| 2 | V _{CC} | bridge supply voltage |
| 3 | GND | ground |
| 4 | +I _{comp} | compensation coil |
| 5 | -I _{comp} | compensation coil |
| 6 | -V _O | bridge output voltage |
| 7 | +V _O | bridge output voltage |
| 8 | -I _{flip} | flip coil |

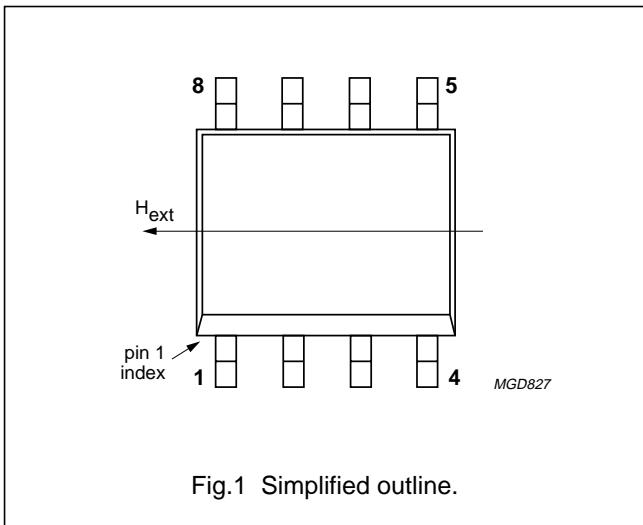


Fig.1 Simplified outline.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | MIN. | TYP. | MAX. | UNIT |
|---------------------|--|------|------|------|---------------------|
| V _{CC} | bridge supply voltage | – | 5 | 8 | V |
| S | sensitivity (uncompensated) | 12 | 16 | – | $\frac{mV/V}{kA/m}$ |
| V _{offset} | offset voltage | -1.5 | – | +1.5 | mV/V |
| R _{bridge} | bridge resistance | 1 | – | 3 | kΩ |
| R _{comp} | compensation coil resistance | 100 | 170 | 300 | Ω |
| A _{comp} | compensation coil field factor; note 1 | 19 | 22 | 25 | $\frac{A/m}{mA}$ |

Magnetic field sensor

KMZ51

| SYMBOL | PARAMETER | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|--|------|------|------|---------------|
| R_{flip} | flip coil resistance | 1 | 2 | 3 | Ω |
| $I_{\text{flip}} \text{ (min)}$ | minimum recommended flipping current; note 2 | 800 | 1000 | 1200 | mA |
| $t_{\text{flip}} \text{ (min)}$ | minimum flip pulse duration; note 2 | 1 | 3 | 100 | μs |

Notes

1. The compensation coil generates a field $H_{\text{comp}} = A_{\text{comp}} \times I_{\text{comp}}$ in addition to the external field H_{ext} . Sensor output will become zero if $H_{\text{ext}} = -H_{\text{comp}}$.
2. Average power consumption of the flipping coil, defined by current, pulse duration and pulse repetition rate may not exceed the specified limit, see Chapter "Limiting values".

CIRCUIT DIAGRAM

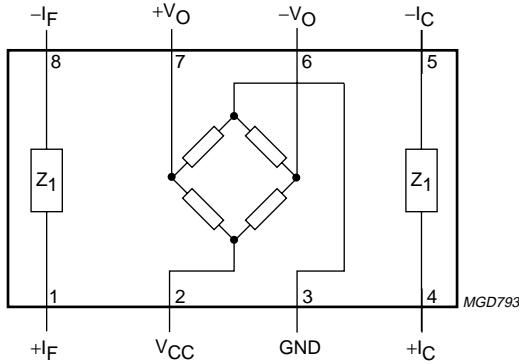


Fig.2 Simplified circuit diagram.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|---------------------------------|--|------|------|--------------------|
| V_{CC} | bridge supply voltage | – | 9 | V |
| P_{tot} | total power dissipation | – | 130 | mW |
| T_{stg} | storage temperature | -65 | +150 | $^{\circ}\text{C}$ |
| T_{bridge} | bridge operating temperature | -40 | +125 | $^{\circ}\text{C}$ |
| I_{comp} | maximum compensation current | – | 15 | mA |
| $I_{\text{flip}} \text{ (max)}$ | maximum flipping current | – | 1500 | mA |
| $P_{\text{flip}} \text{ (max)}$ | maximum flipping power dissipation | – | 50 | mW |
| V_{isol} | voltage between isolated systems: flip coil and Wheatstone bridge; compensation coil and Wheatstone bridge; flip coil and compensation coil | – | 60 | V |

Magnetic field sensor

KMZ51

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|---------------|---|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | 155 | K/W |

CHARACTERISTICS

 $T_{amb} = 25^\circ C$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|---|--|------|-------|-------|---------------------|
| V_{CC} | bridge supply voltage | | – | 5 | 8 | V |
| H_y | operating range in sensitive direction | | –0.2 | – | +0.2 | kA/m |
| H_x | operating range perpendicular to sensitive direction | | –0.2 | – | +0.2 | kA/m |
| S | sensitivity | open circuit | 12 | 16 | – | $\frac{mV/V}{kA/m}$ |
| TCS | temperature coefficient of sensitivity | $T_s = -25$ to $+125^\circ C$ | – | 0.31 | – | %/K |
| TCV_O | temperature coefficient of output voltage | $V_{CC} = 5 V$; $T_{amb} = -25$ to $+125^\circ C$ | – | –0.4 | – | %/K |
| | | $I_{CC} = 3 mA$; $T_{amb} = -25$ to $+125^\circ C$ | – | –0.1 | – | %/K |
| R_{bridge} | bridge resistance | resistance pins 2 to 3 | 1 | – | 3 | $k\Omega$ |
| TCR_{bridge} | temperature coefficient of bridge resistance | $T_{bridge} = -25$ to $+125^\circ C$ | – | 0.3 | – | %/K |
| V_{offset} | offset voltage | | –1.5 | 0 | +1.5 | mV/V |
| TCV_{offset} | temperature coefficient of offset voltage | $T_{bridge} = -25$ to $+125^\circ C$ | –3 | 0 | +3 | $\frac{\mu V/V}{K}$ |
| FH | hysteresis of output voltage | | – | – | 2 | %FS |
| R_{comp} | resistance of compensation coil | resistance pins 4 to 5 | 100 | 170 | 300 | Ω |
| A_{comp} | field factor of compensation coil | | 19 | 22 | 25 | $\frac{A/m}{mA}$ |
| R_{flip} | resistance of set/reset conductor | resistance pins 1 to 8 | 1 | 2 | 3 | Ω |
| TCR_{flip} | temperature coefficient of resistance of set/reset coil | $T_{flip} = -25$ to $+125^\circ C$ | – | 0.39 | – | %/K |
| I_{flip} | recommended flipping current for stable operation | | ±800 | ±1000 | ±1200 | mA |
| t_{flip} | flip pulse duration | | 1 | 3 | 100 | μs |
| R_{isol} | isolating resistance | resistance pins 1 to 2, 1 to 4 and 2 to 4 | 1 | – | – | $m\Omega$ |
| V_{isol} | voltage between isolated systems | voltage pins 1 to 2, 1 to 4 and 2 to 4 | – | – | 50 | V |
| f | operating frequency | | 0 | – | 1 | MHz |

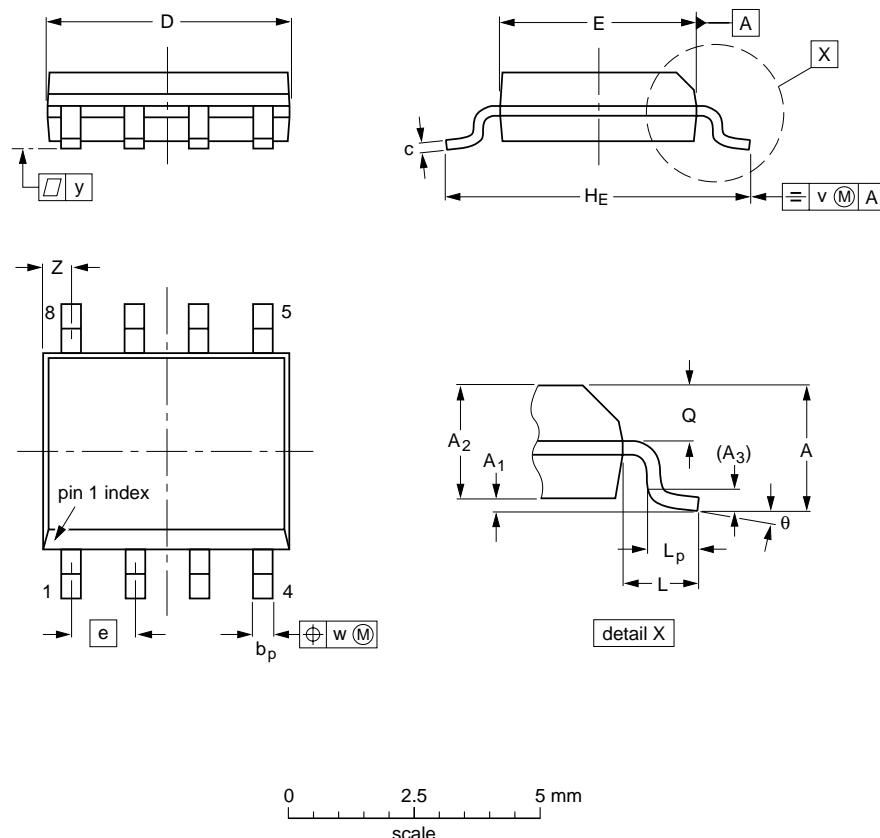
Magnetic field sensor

KMZ51

PACKAGE OUTLINE

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽²⁾ | e | H _E | L | L _p | Q | v | w | y | Z ⁽¹⁾ | θ |
|--------|----------------|----------------|----------------|----------------|----------------|------------------|------------------|------------------|-------|----------------|-------|----------------|----------------|------|------|-------|------------------|----------|
| mm | 1.75 0.10 | 0.25 1.25 | 1.45 | 0.25 | 0.49 0.36 | 0.25 0.19 | 5.0 4.8 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8° 0° |
| inches | 0.069 0.004 | 0.010 0.049 | 0.057 | 0.01 | 0.019 0.014 | 0.0100 0.0075 | 0.20 0.19 | 0.16 0.15 | 0.050 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.024 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | |

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|------|--|------------------------|----------------------|
| | IEC | JEDEC | EIAJ | | | |
| SOT96-1 | 076E03 | MS-012 | | | | 97-05-22 99-12-27 |

Magnetic field sensor

KMZ51

DATA SHEET STATUS

| DATA SHEET STATUS | PRODUCT STATUS | DEFINITIONS ⁽¹⁾ |
|---------------------------|----------------|--|
| Objective specification | Development | This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice. |
| Preliminary specification | Qualification | This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product. |
| Product specification | Production | This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product. |

Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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KMZ51

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